# Rayson Bluetooth ® Module

## **Low Energy Smart Module**

**BTM-800** 

### <u>Features</u> <u>Outline</u>

- Bluetooth standard V4.1 conformity.
- CSR1010 chip
- Programmable general purpose PIO controller :
- Wide supply voltage range 1.8 to 3.6V.
- I2C for EEPROM and ICs peripherals.
- -87dBm Bluetooth low energy RX sensitivity.
- 12 digital PIOs
- 3 analogue AlOs
- 4 PWM modules
- Option for built-in G-sensor
- Wake-up interrupt and Watchdog time
- RoHS Compliant
- Dimension: 20 x 12 x2.0mm

### **Applications**

- Sports and fitness
- Health care
- Automotive

Deep sleep

- Home appliance
- Office and mobile accessories
- Low rate data communications



#### **Electrical Characteristics**

Absolute Ma	ıximum Ratings			
Ratings		Min.	Max.	
Storage Temp	erature	-30 ℃		
Supply Voltage	e(VDD_PADS,VDD_BAT)	1.8V	3.6 V	
Recommend	led Operating Condition		·	
Operating Con	dition	Min.	Max.	
Operating Tem	perature range	-20 ℃		
Supply voltage	(VDD_PADS,VDD_BAT)	1.8V	3.6V	
Current Cor	sumption (CSR1010 QFN total typical current consumption	on measu	red from the battery	supply)
Mode	Descrisption Typical Current at 3V			nt at 3V
Dormant	functions are shutdown. To wake up toggle the WAKE pin <900nA			

<5µA

VDD\_PADS = ON, REFCLK = OFF, SLEEPCLK = ON,

VDD BAT = ON, RAM = ON, digital circuits = ON,

SMPS = ON (low-power mode), 1ms wake-up time

Idle	VDD_PADS = ON, REFCLK = ON, SLEEPCLK = ON,	~1mA
	VDD_BAT = ON, RAM = ON, digital circuits = ON,	
	MCU = IDLE, <1µs wake-up time	
RX / TX active	-	peak current 16mA @ 3V

# **RF Specification:**

Battery Supply=3V, Temperature=+20 $^{\circ}$ C

### **Transmitter**

	Min	Тур	Max	Bluetooth	Unit
				Specification	
Maximum RF transmit power (conductive)	-4	0	+2	-6 to +4	dBm
Initial carrier frequency tolerance	-40	-	+40	±75	kHz
Δf1avg maximum modulation	225	258	275	225 < f1avg < 275	
Δf2max minimum modulation	185	197		≥185	
Δf2avg/Δf1avg		0.8	0.86	≥0.8	
Carrier drift rate	-	8	-	≤20	kHz/50µ
Carrier drift	-	7	-	≤50	kHz
2nd Harmonic Content	-	-46	-	≤-30	dBm
3rd Harmonic Content	-	-45	-	≤-30	dBm

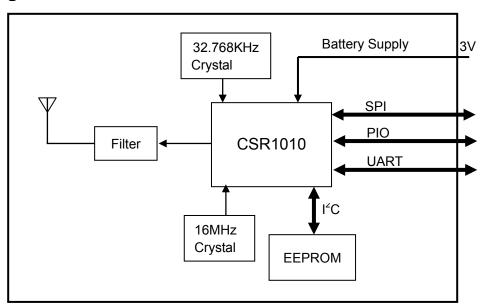
### Receiver

Battery Supply=3V, Temperature=+20°C

	Frequency (GHz)	Min	Тур	Max	Bluetooth Specification	Unit
Sensitivity at 30.8%	2.402	-	-87	-84	≤-70	dBm
PER for all basic rate	2.440	-	-87	-84		
packet types (conductive)	2.480	_	-87	-84		
Maximum received signal at 30.8% PER			>-10		≥-10	dBm
C/I co-channel		_	6	21	≤21	dB
Adjacent channel selectivity C/I		-	2	15	≤15	dB
F = F0 + 1MHz						
Adjacent channel selectivity C/I		-	1	15	≤15	dB
F = F0 - 1MHz						
Adjacent channel selectivity C/I		-	-28	-17	≤-17	dB
F = F0 + 2MHz						
Adjacent channel selectivity C/I			-21	-15	≤-15	dB
F = F0 - 2MHz						

Adjacent channel selectivity C/I		-31	-27	≤-27	dB
F = F0 + 3MHz					
Adjacent channel selectivity C/I	-	-30	-27	≤-27	dB
F = F0 - 5MHz					
Adjacent channel selectivity C/I		-24	-9	≤-9	dB
F = FImage					
Maximum level of intermodulation		-50	-33	≥-50	dBm
interferers					
Spurious output level	-	-154	-		dBm/Hz

### **Block Diagram**



#### **UART Interface**

The BTM800 UART interface provides a simple mechanism for communicating with other serial devices using the RS232 protocol.

2 signals implement the UART function, UART\_TX and UART\_RX. When BTM800 is connected to another digital device via UART interface, the data is exchanged by UART\_RX and UART\_TX and, the hardware flow control is not available. UART configuration parameters such as baud rate, stop bits and parity bit are set by BTM800's firmware.

As set for UART communications, the general PIO ports PIO[0] and PIO[1] are assigned as UART\_TX (output) and UART\_RX (input).

Note: To communicate with the UART at its maximum data rate using a standard PC, the PC requires an accelerated serial port adapter card.

The following table shows the possible UART settings for the BTM800:

Parameter		Possible Values
Baud rate Minimum		1200 baud (≤2%Error)
Baud rate	Willimum	9600 baud (≤1%Error)
	Maximum	2M baud (≤1%Error)

Parity	None, Odd or Even
Number of stop bits	1 or 2
Bits per byte	8

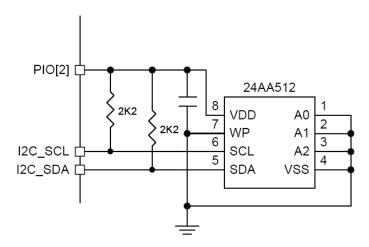
The maximum baud rate is 2400 baud during deep sleep.

As the actual throughput of BLE air traffic is around 2400 baud, higher baud rate setting at UART interface can cause data congestion. Software flow control may required to avoid data loss.

#### I<sup>2</sup>C Interface

There is I<sup>2</sup>C interface of CSR1010 is dedicated for EEPROM connections. The EEPROM usually hold the program code that will be load to CSR1010 during boot up. The BTM800 has the 128K EEPROM built in for the program code.

If extra I<sup>2</sup>C interface is required for applications, the software emulated I<sup>2</sup>C interface can be implemented on general PIO ports.



Example of an I<sup>2</sup>C Interface EEPROM Connection

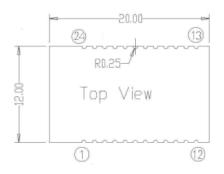
#### **BTM-800 Pins Function**

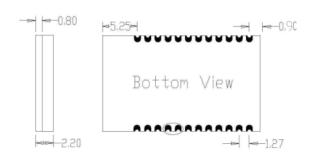
No.	Pin Name	Pin Type	Supply Domain	Pin description
1	PIO[3]	Bi-directional	VDD_PADS	Programmable input/output line or PWN signal output
2	PIO[4]	Bi-directional	VDD_PADS	Programmable input/output
3	SPI_CLK( PIO5)	Bi-directional	VDD_PADS	Programmable input/output or debug SPI_CLK selected
4	SPI_CSB( PIO6)	Bi-directional	VDD_PADS	Programmable input/output or debug SPI chip selected
5	SPI_MOSI( PIO7)	Bi-directional	VDD_PADS	Programmable input/output or debug SPI_MOSI selected
6	SPI_MISO(PIO8)	Bi-directional	VDD_PADS	Programmable input/output or debug SPI_MISO selected
7	PIO[9]	Bi-directional	VDD_PADS	Programmable input/output line
8	PIO[10]	Bi-directional	VDD_PADS	Programmable input/output line
9	PIO[11]	Bi-directional	VDD_PADS	Programmable input/output line or button input

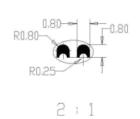
10	3V	Power input		Connect to external 3V (battery) ,we advise to connect a decoupling capacitor to this pin and it should be more than 47uF.
11	GND	GND		Common ground
12	PIO2	Bi-directional	VDD_PADS	Provide I2C or SPI Power , pls leave it NC if don't use it.
13	WAKE	Bi-directional	VDD_BAT	Input to wake module from domand/hibernate mode. if no
				use, pls pull down.
14	I2C-SCL	Bi-directional	VDD_PADS	I2C clock or SPI serial flash clock output(SF_CLK)
15	I2C-SDA	Bi-directional	VDD_PADS	I2C data input/output or SPI serial flash data
16	AIO(2)	Bi- Analogue	VDD_AUX (1.35V)	Analogue Programmable input/output line
17	AIO(1)	Bi- Analogue	VDD_AUX (1.35V)	Analogue Programmable input/output line
18	AIO(0)	Bi- Analogue	VDD_AUX (1.35V)	Analogue Programmable input/output line
19	UART TX	Bi-directional	VDD_PADS	Programmable input/output or UART TX
20	UART RX	Bi-directional	VDD_PADS	Programmable input/output or UART RX
21	SPI_PIO#_SEL	Bi-directional	VDD_PADS	Programmable input/output or SPI/PIO selected,set HI for
				SPI
22	GND	GND		Common ground
23	RF_IN	Analogue	VDD_BT_RADIO	Antenna interface Request
24	GND	GND		Common ground

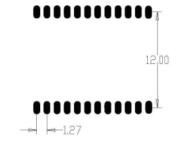
### **Dimension:**

Unit: mm

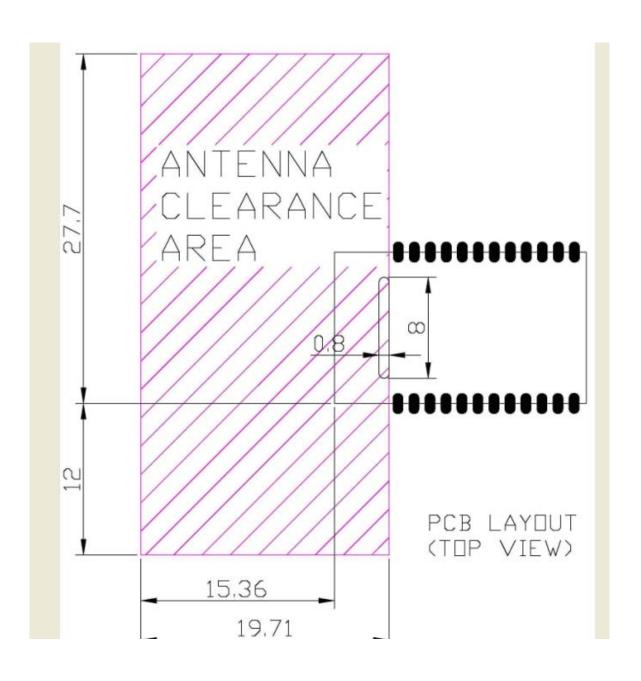








PCB Layout(Top View)



### **Reflow Profile**

Reflow profile requirements					
Parameter Specification	Referenc	Specification			
Average temperature gradient in preheating		1~2.5°C/s to 175°C equilibrium.			
Soak time	T <sub>soak</sub>	120~180 seconds			
Time above 217°C (T <sub>1</sub> )	t <sub>1</sub>	45~90 seconds			
Peak temperature in reflow	Т2	250°C (-0/+5°C)			
Time at peak temperature	t <sub>2</sub>	6 seconds			
Temperature gradient in cooling		6°C/second max.			

